

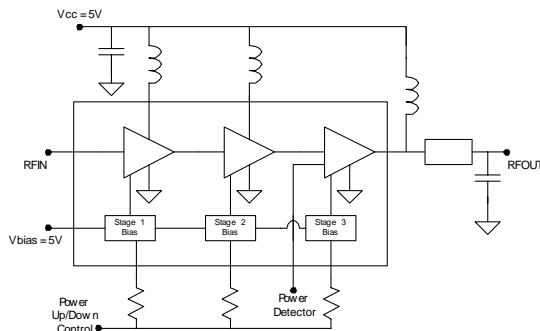


Product Description

Sirenza Microdevices' SZM-2066Z is a high linearity class AB Heterojunction Bipolar Transistor (HBT) amplifier housed in a low-cost surface-mountable plastic Q-FlexN multi-chip module package. This HBT amplifier is made with InGaP on GaAs device technology and fabricated with MOCVD for an ideal combination of low cost and high reliability.

This product is specifically designed as a final or driver stage for 802.16 and 802.11b/g equipment in the 2.4-2.7 GHz bands. It can run from a 3V to 5V supply. The external output match and bias adjustability allows load line optimization for other applications or over narrower bands. It features an output power detector, on/off power control and high RF overdrive robustness. This product features a RoHS compliant and Green package with matte tin finish, designated by the 'Z' suffix.

Functional Block Diagram



Key Specifications

Symbol	Parameters: Test Conditions, 2.5-2.7GHz App circuit, $Z_0 = 50\Omega$, $V_{CC} = 5.0V$, $I_q = 583mA$, $T_{BP} = 30^\circ C$	Unit	Min.	Typ.	Max.
f_O	Frequency of Operation	MHz	2500		2700
P_{1dB}	Output Power at 1dB Compression – 2.7GHz	dBm	32.0	33.5	
S_{21}	Small Signal Gain – 2.7GHz	dB	32.2	33.7	
Pout	Output power at 2.5% EVM 802.11g 54Mb/s - 2.7GHz	dBm		26.0	
IM3	Third Order Suppression (Pout=23dBm per tone) - 2.7GHz	dBc		-45	-40
NF	Noise Figure at 2.7 GHz	dB		7.7	
IRL	Worst Case Input Return Loss 2.5-2.7GHz	dB	7.5	10.5	
ORL	Worst Case Output Return Loss 2.5-2.7GHz		12.5	15.5	
Vdet Range	Output Voltage Range for Pout=10dBm to 33dBm	V		0.9 to 1.8	
I_{cq}	Quiescent Current ($V_{CC} = 5V$)	mA	503	583	663
I_{VPC}	Power Up Control Current ($V_{pc}=5V$, ($I_{VPC1} + I_{VPC2} + I_{VPC3}$))	mA		4	
I_{leak}	Vcc Leakage Current ($V_{CC} = 5V$, $V_{pc} = 0V$)	μA			50
$R_{th, j-l}$	Thermal Resistance (junction - lead)	$^\circ C/W$		10	

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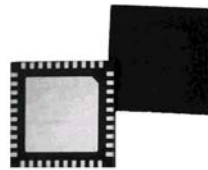
Phone: (800) SMI-MMIC

<http://www.sirenza.com>
EDS-104641 Rev C

Preliminary

SZM-2066Z

2.4-2.7GHz 2W Power Amplifier



6mm x 6mm QFN Package



RoHS Compliant
& Green Package

Product Features

- $P_{1dB} = 33.5dBm @ 5V$
- Three Stages of Gain: 37dB
- 802.11g 54Mb/s Class AB Performance
- Pout = 26dBm @ 2.5% EVM, Vcc 5V, 690mA
- Active Bias with Adjustable Current
- On-chip Output Power Detector
- Low Thermal Resistance
- Power up/down control < 1 μs

Applications

- 802.16 WiMAX Driver or Output Stage
- 802.11b/g WLAN, WiFi

Typical Performance with appropriate app circuit(Vcc=5V, Icq=583mA, * 802.11g 54Mb/s 64QAM)

Parameter	Units	**2.4GHz	2.5GHz	2.6GHz	2.7GHz
Gain @ Pout=26dBm	dB	37.5	36.9	36.5	34.6
P1dB	dBm	34.6	33.5	33.5	33.9
Pout @ 2.5% EVM*	dBm	27	26	26	26.5
Current @ Pout 2.5% EVM*	mA	703	710	700	712
Input Return Loss	dB	-12.1	-11.5	-10.8	-10.5
Output Return Loss	dB	-27	-15.6	-28	-18.5

**Measured with 2.4-2.5GHz Application circuit. See page 11 for details.

Absolute Maximum Ratings

Parameters	Value	Unit
VC3 Collector Bias Current (I _{VC3})	1500	mA
VC2 Collector Bias Current (I _{VC2})	500	mA
VC1 Collector Bias Current (I _{VC1})	150	mA
****Device Voltage (V _D)	9.0	V
Power Dissipation	6	W
Operating Lead Temperature (T _L)	-40 to +85	°C
***Max CW RF output Power for 50 ohm continuous long term operation	30	dBm
Max CW RF Input Power for 50 ohm output load	26	dBm
Max CW RF Input Power for 10:1 VSWR RF out load	5	dBm
Storage Temperature Range	-40 to +150	°C
Operating Junction Temperature (T _J)	+150	°C
ESD Human Body Model	1000	V

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH} \text{ J}^1$$

*** With specified application circuit.

**** No RF Drive


Caution: ESD Sensitive

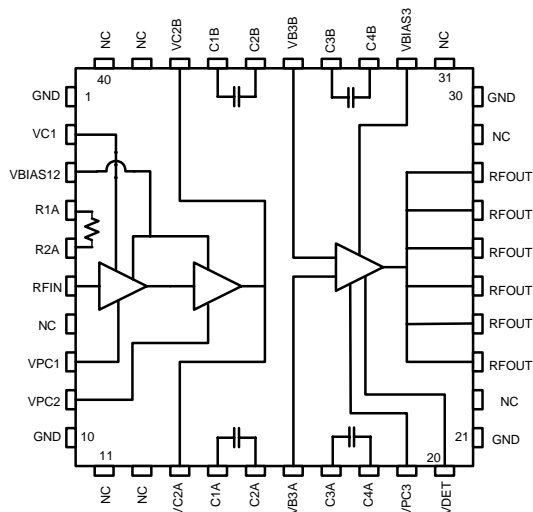
Appropriate precaution in handling, packaging and testing devices must be observed.



SZM-2066Z 2.4-2.7GHz 2W Power Amp

Pin Out Description

Simplified Device Schematic

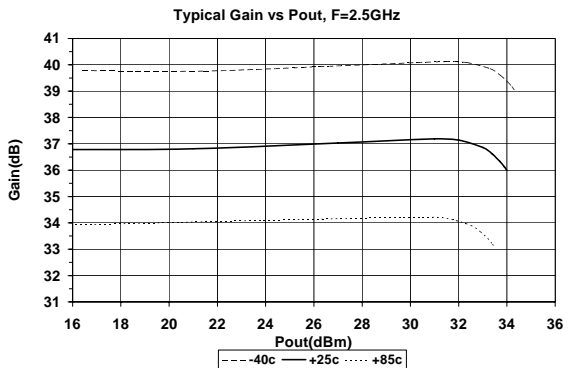
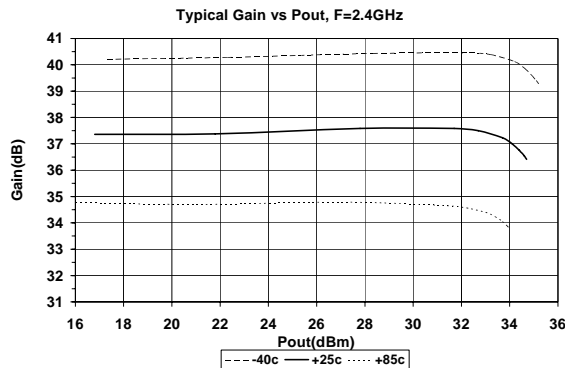
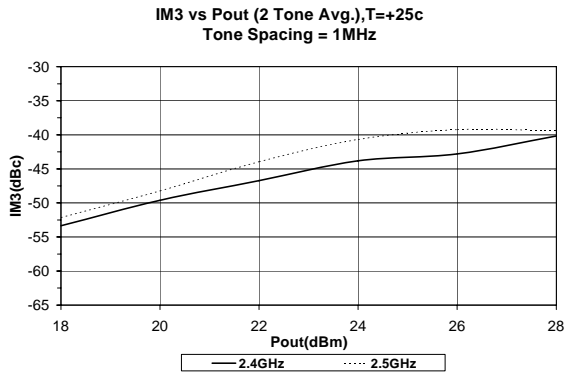
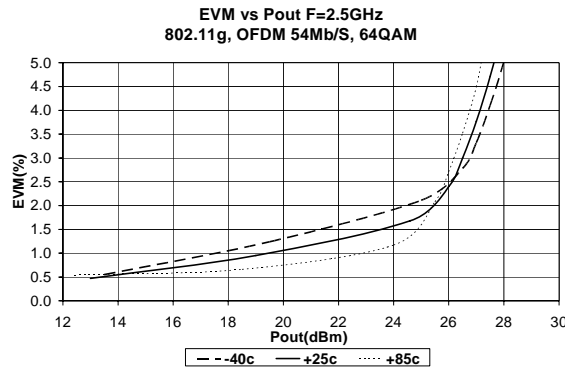
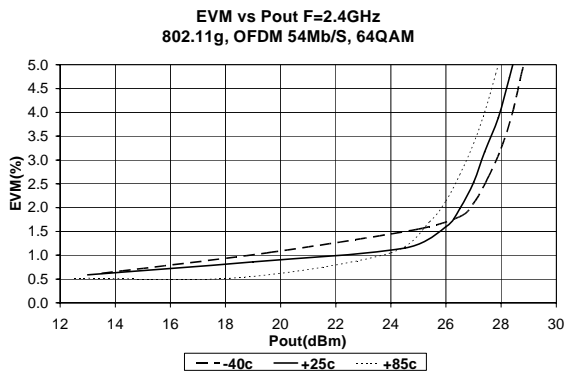
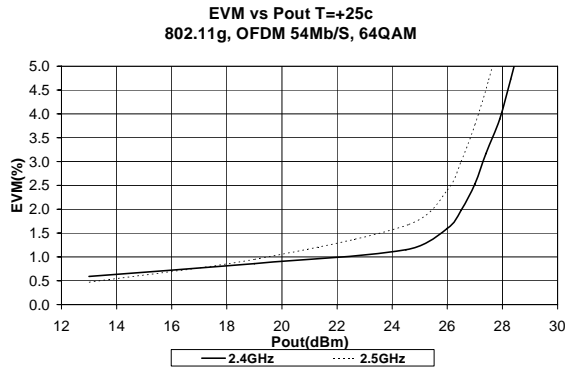




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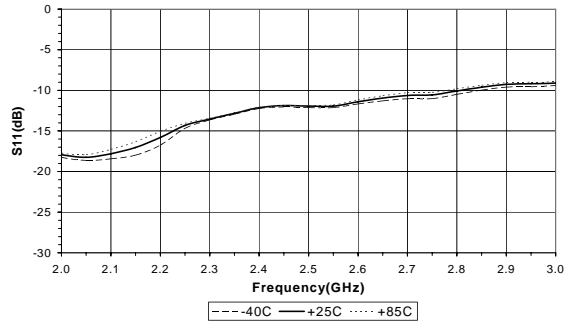
SZM-2066Z 2.4-2.7GHz 2W Power Amp

Measured 2.4-2.5 GHz Application Circuit Data ($V_{cc} = V_{pc} = 5.0V$, $I_q = 556mA$, $T=25C$)

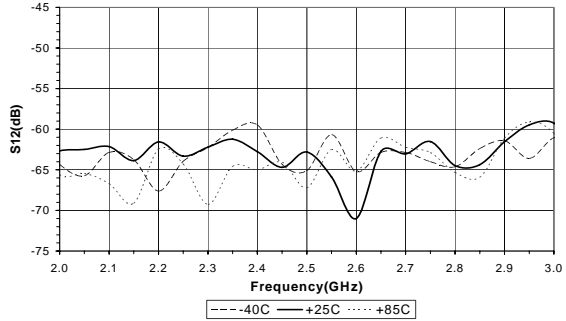


Measured 2.4-2.5 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.0V$, $I_q = 556mA$, $T=25C$)

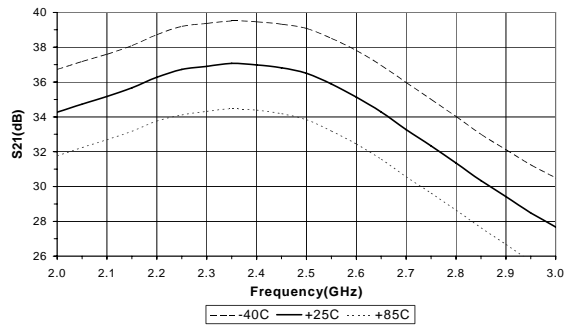
Narrowband S11 - Input Return Loss



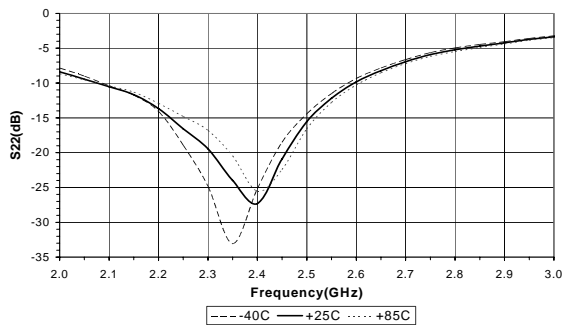
Narrowband S12 - Reverse Isolation



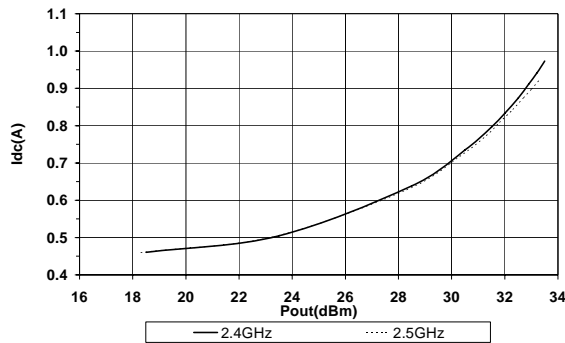
Narrowband S21 - Forward Gain



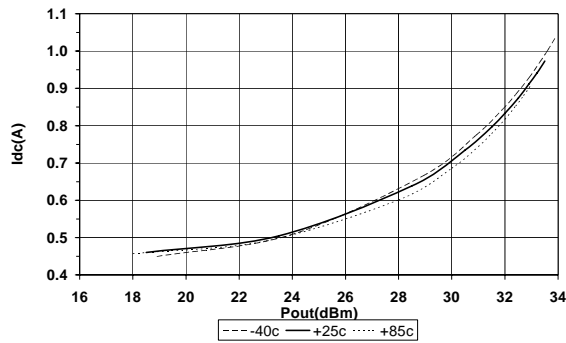
Narrowband S22 - Output Return Loss



DC Supply Current vs Pout, T=+25C



DC Supply Current vs Pout, F=2.4GHz

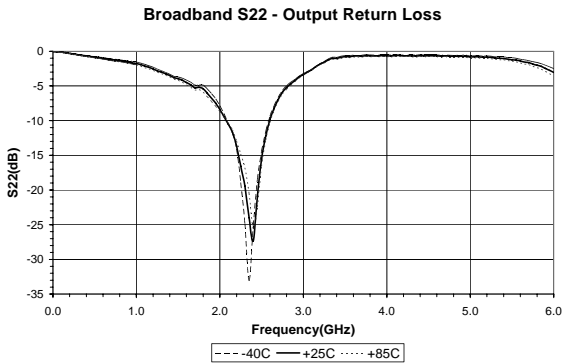
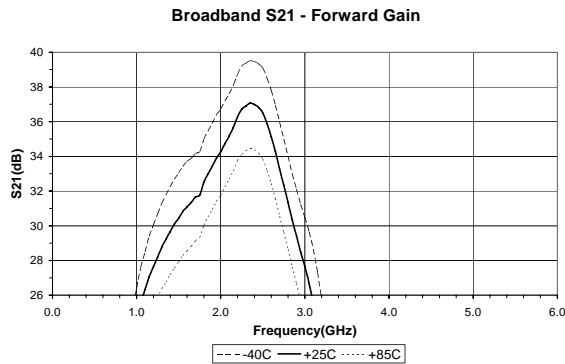
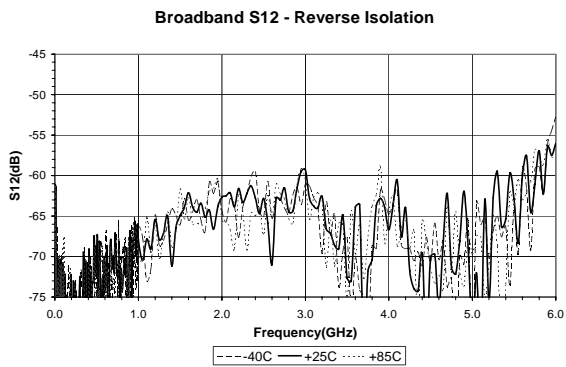
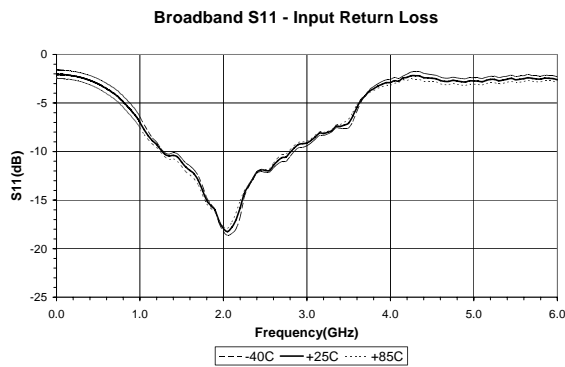
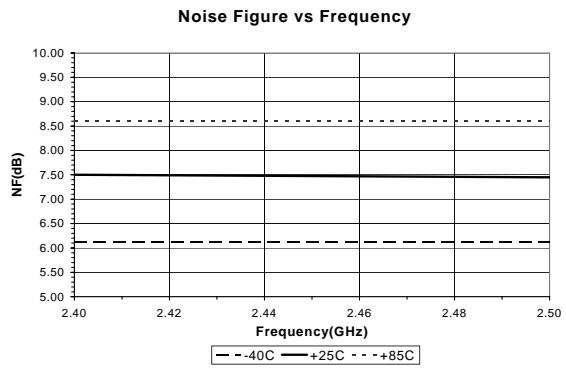
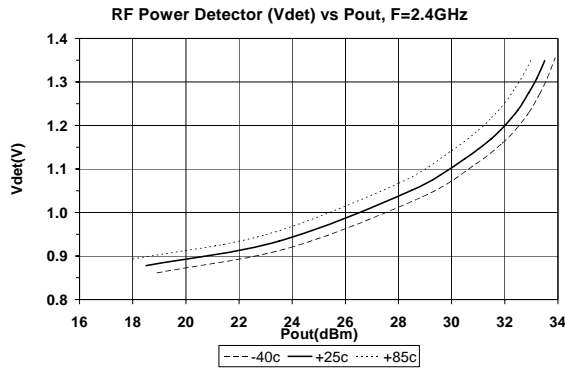




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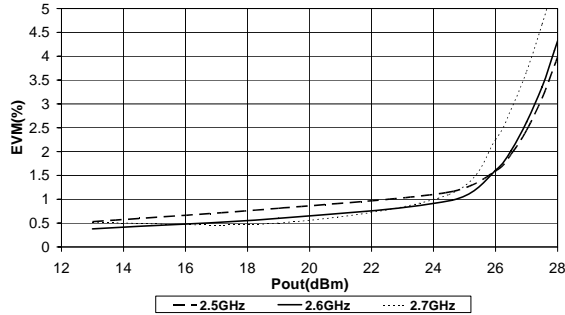
SZM-2066Z 2.4-2.7GHz 2W Power Amp

Measured 2.4-2.5 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.0V$, $I_q = 556mA$, $T=25C$)

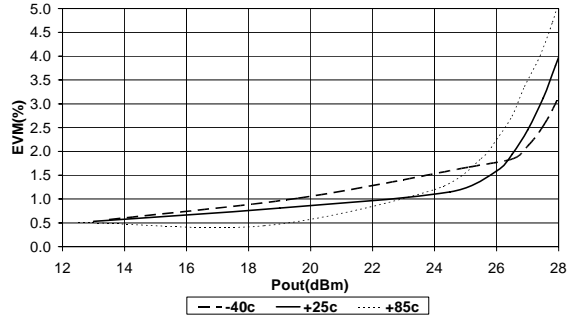


Measured 2.5-2.7 GHz Application Circuit Data ($V_{cc} = V_{pc} = 5.0V$, $I_q = 583mA$, $T=25C$)

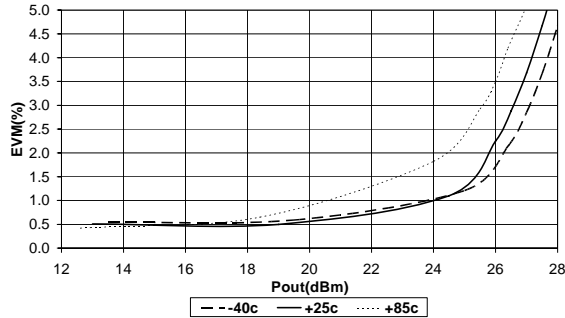
EVM vs Pout T=+25c
802.11g, OFDM 54Mb/S, 64QAM



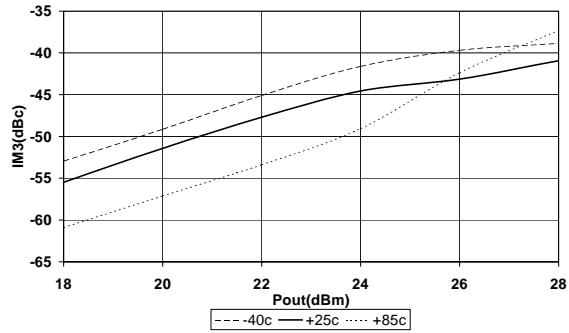
EVM vs Pout F=2.5GHz
802.11g, OFDM 54Mb/S, 64QAM



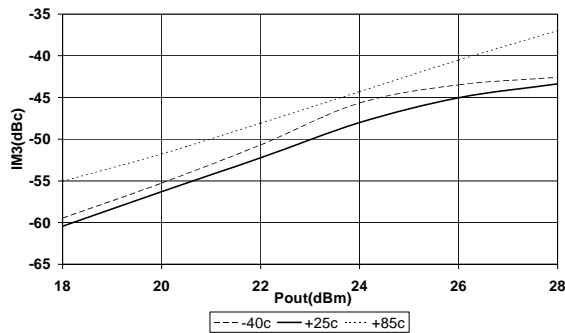
EVM vs Pout F=2.7GHz
802.11g, OFDM 54Mb/S, 64QAM



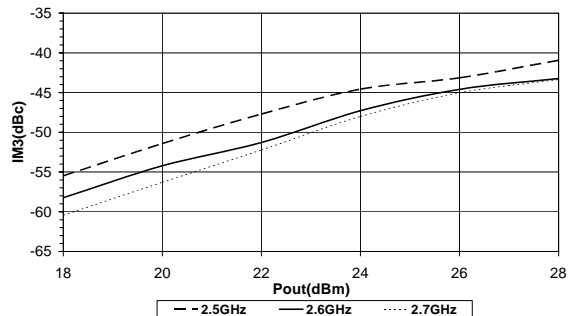
IM3 vs Pout (2 tone avg.), F=2.5GHz



IM3 vs Pout (2 tone avg.), F=2.7GHz



IM3 vs Pout (2 Tone Avg.), T=+25c
Tone Spacing = 1MHz



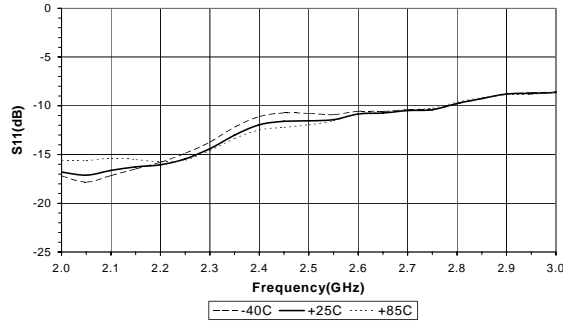


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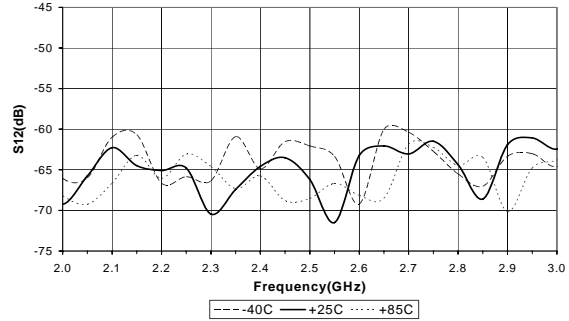
SZM-2066Z 2.4-2.7GHz 2W Power Amp

Measured 2.5-2.7 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.0V$, $I_q = 583mA$, $T=25C$)

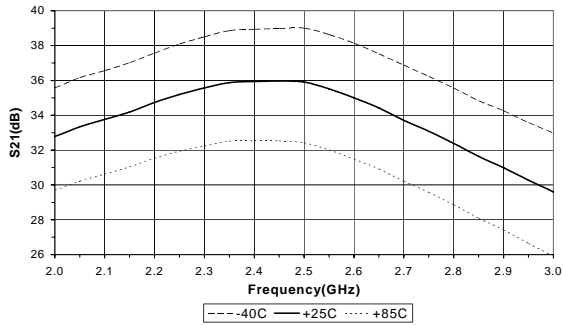
Narrowband S11 - Input Return Loss



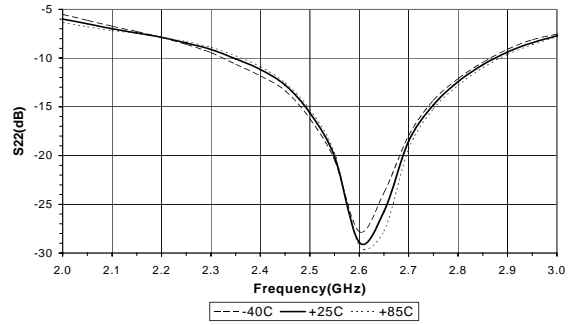
Narrowband S12 - Reverse Isolation



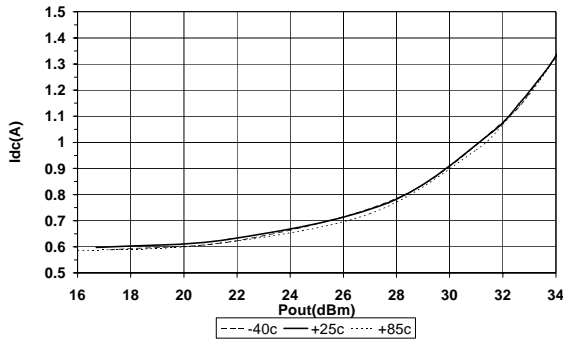
Narrowband S21 - Forward Gain



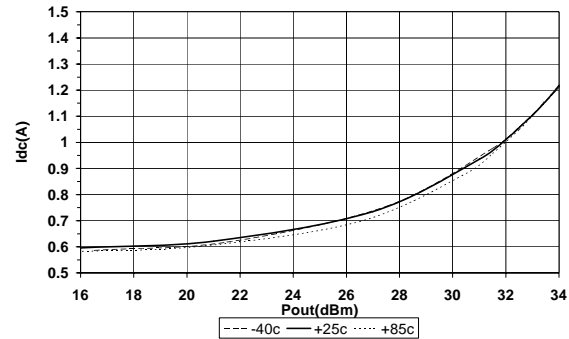
Narrowband S22 - Output Return Loss



DC Supply Current vs Pout, F=2.5GHz



DC Supply Current vs Pout, F=2.7GHz

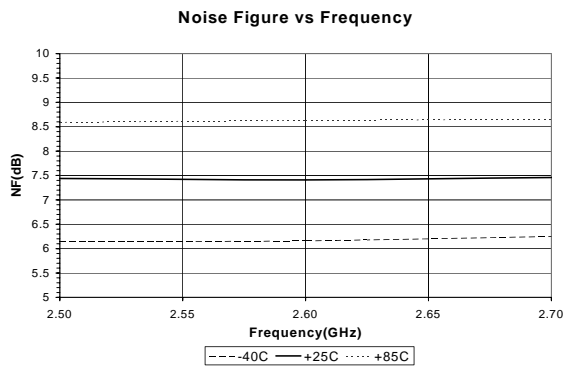
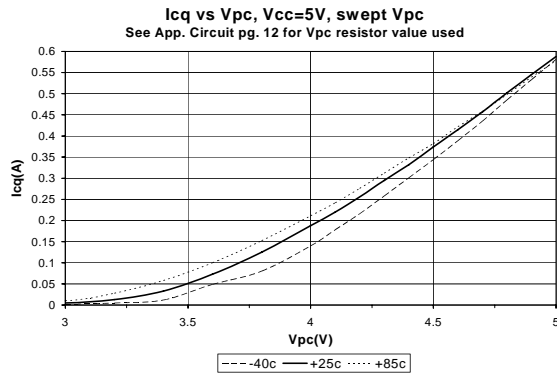
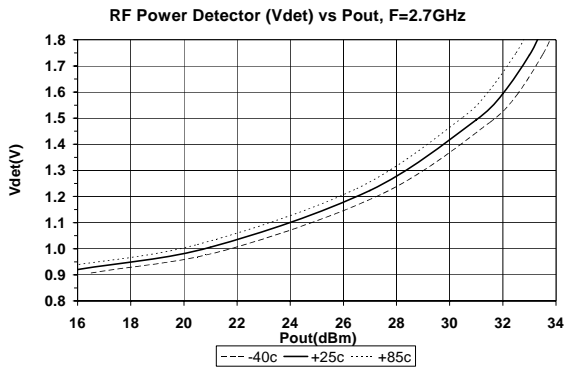
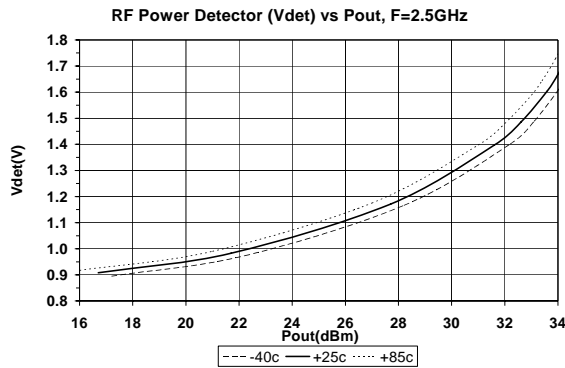




Preliminary

SZM-2066Z 2.4-2.7GHz 2W Power Amp

Measured 2.5-2.7 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.0V$, $I_q = 583mA$, $T=25C$)



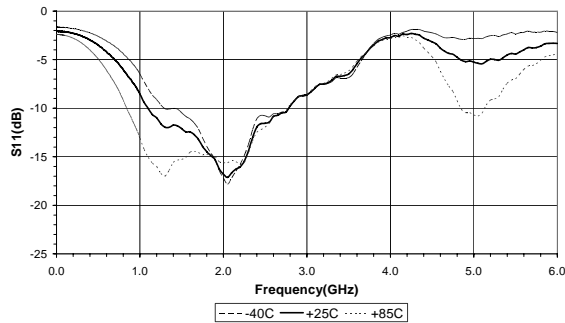


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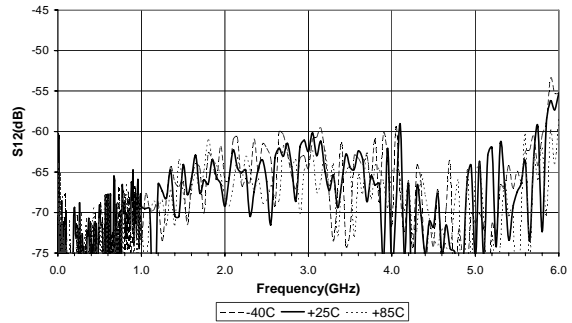
SZM-2066Z 2.4-2.7GHz 2W Power Amp

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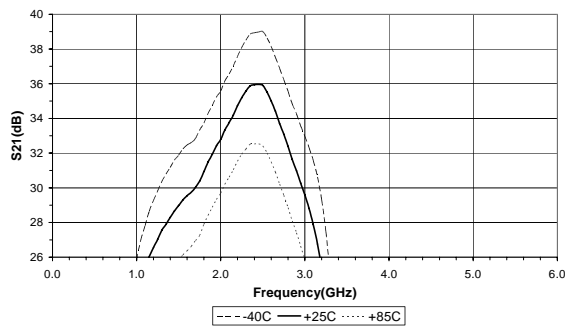
Broadband S11 - Input Return Loss



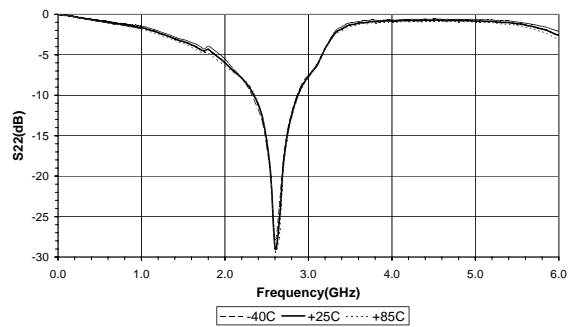
Broadband S12 - Reverse Isolation



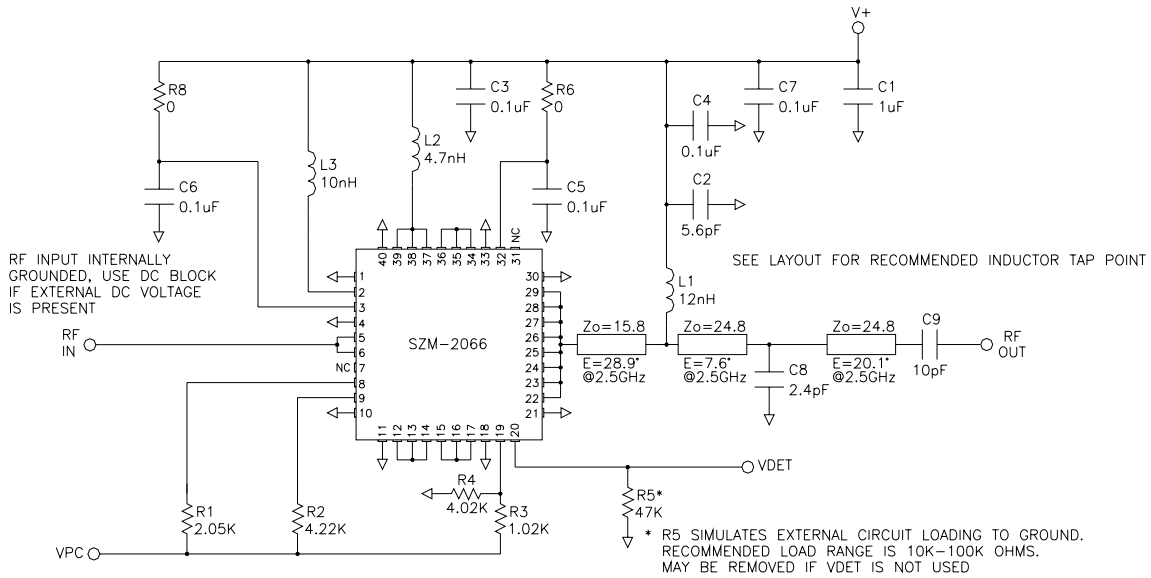
Broadband S21 - Forward Gain



Broadband S22 - Output Return Loss



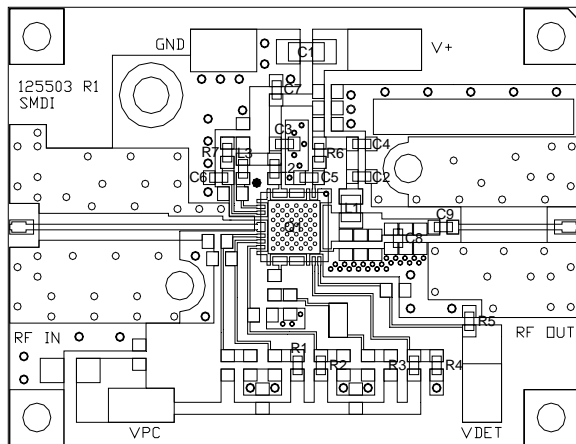
2.4-2.5 GHz Evaluation Board Schematic For $V_{CC} = V_+ = V_{PC} = 5.0V$



Note: For power up enable (V_{PC}) voltages < 5V, contact Applications Engineering for the appropriate R1, R2, R3, and R4 values.

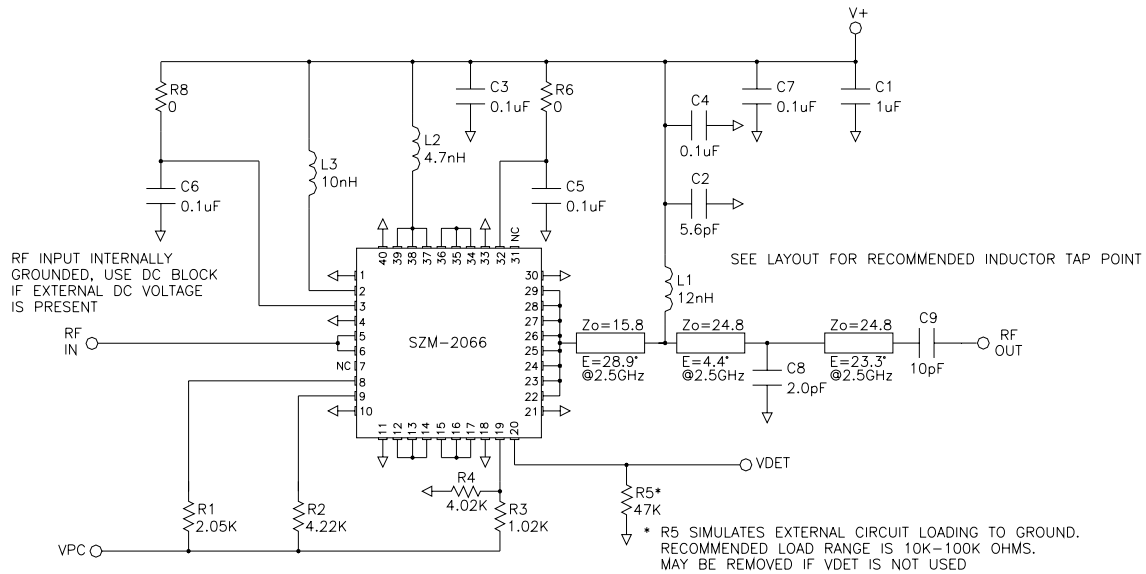
2.4-2.5 GHz Evaluation Board Layout For $V_{CC} = V_+ = V_{PC} = 5.0V$

Board material GETEK, 10mil thick, Dk=3.9, 2 oz. copper



DESG	DESCRIPTION	NOTES
Q1	SZM-2066	6x6mm QFN
R1	2.05K OHM, 0603 1%	0402 may be used
R2	4.22K OHM, 0603 1%	"
R3	1.02K OHM, 0603 1%	"
R4	4.02K OHM, 0603 1%	"
R5	47K OHM, 0603	"
R6,7	0 OHM, 0603	"
C1	1uF 16V MLCC CAP	Tantalum ok for EVM performance. Use MLCC type for best IM3 levels
C2	5.6pF CAP, 0603	NPO ROHM MCH185A5R60K or equiv.
C3,4,5,6,7	0.1uF CAP, 0603	NPO 0402 ok ROHM MCH184CN105K or equiv.
C8	2.4pF CAP, 0603	NPO, low ESR ATC 600S2R0CW250 or equiv.
C9	10pF CAP, 0603	NPO, low ESR ATC 600S100JW250 or equiv.
L1	12nH IND 0805	Coilcraft 0805HQ - 12NXJB
L2	4.7nH IND, 0603	TOKO 0603 - LL1608FH4N7J
L3	10nH IND, 0603	TOKO 0603 - LL1608FH10N

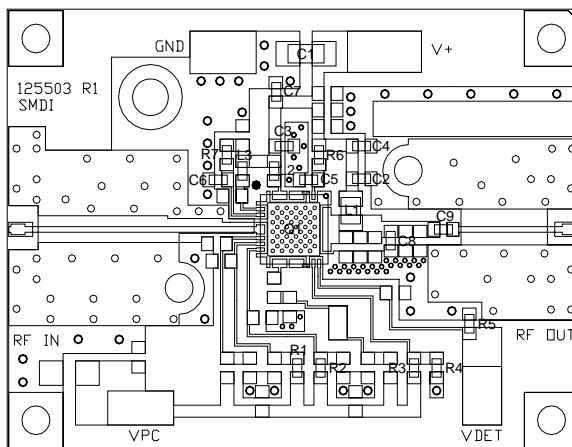
2.5-2.7 GHz Evaluation Board Schematic For $V_{CC} = V_+ = V_{PC} = 5.0V$



Note: For power up enable (Vpc) voltages < 5V, contact Applications Engineering for the appropriate R1, R2, R3, and R4 values.

2.5-2.7 GHz Evaluation Board Layout For $V_{CC} = V_+ = V_{PC} = 5.0V$

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R5	47K OHM, 0603	"
R6,7	0 OHM, 0603	"
C1	1uF 16V MLCC CAP	Tantalum ok for EVM performance. Use MLCC type for best IM3 levels
C2	5.6pF CAP, 0603	NPO ROHM MCH185A5R60K or equiv.
C3,4,5,6,7	0.1uF CAP, 0603	NPO 0402 ok ATC 600S2R0CW250 or equiv.
C8	2.0pF CAP, 0603	NPO, low ESR ATC 600S2R0CW250 or equiv.
C9	10pF CAP, 0603	NPO, low ESR ATC 600S100JW250 or equiv.
L1	12nH IND 0805	Coilcraft 0805HQ - 12NXJBB
L2	4.7nH IND, 0603	TOKO 0603 - LL1608FH4N7J
L3	10nH IND, 0603	TOKO 0603 - LL1608FH10NJ



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SZM-2066Z 2.4-2.7GHz 2W Power Amp

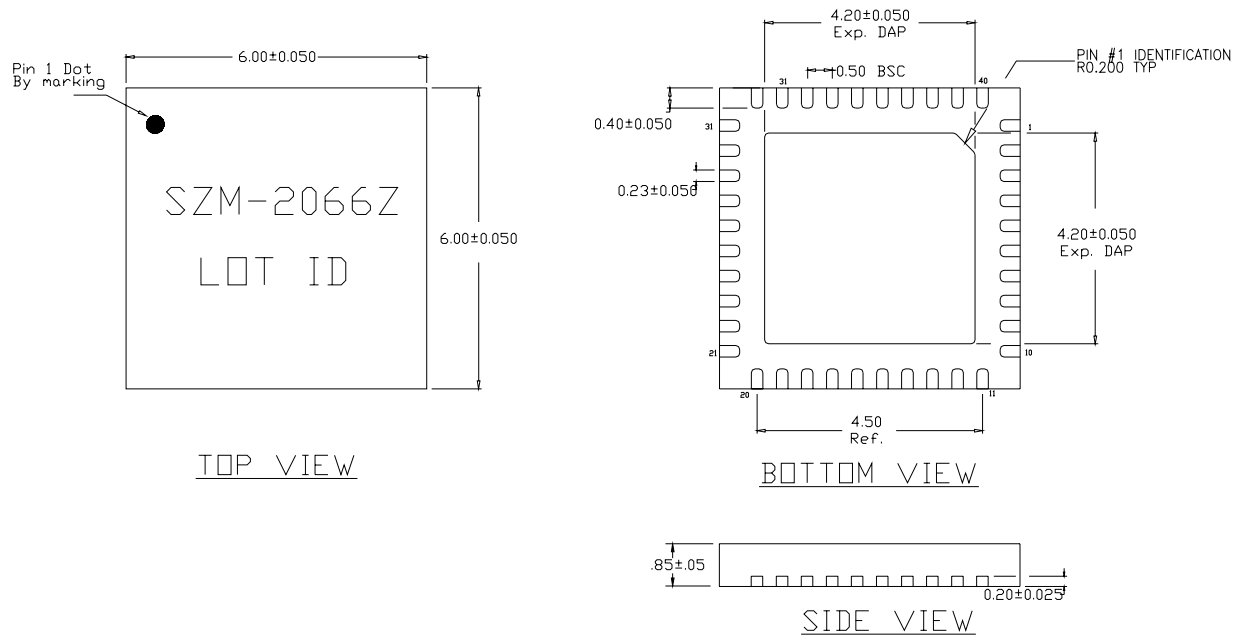
Part Symbolization

The part will be symbolized with "SZM-2066Z" to designate it as a RoHS green compliant product. Marking designator will be on the top surface of the package.

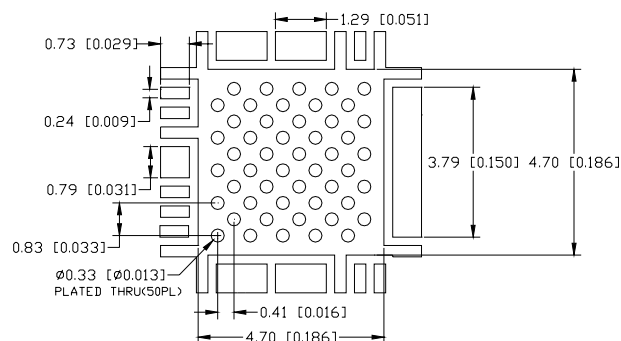
Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SZM-2066Z	13"	3000

Package Outline Drawing (dimensions in mm):



Recommended Metal Land Pattern (dimensions in mm[in]):



Recommended PCB Soldermask for Land Pattern (dimensions in mm[in]):

